## **TOSHIBA**

## TC5116100BSI-60/70

**PRELIMINARY** 

### 16,777,216 WORD X 1 BIT DYNAMIC RAM

#### Description

The TC5116100BSJ is the new generation dynamic RAM organized 16,777,216 word by 1 bit. The TC5116100BSJ utilizes Toshiba's CMOS silicon gate process technology as well as advanced circuit techniques to provide wide operating margins, both internally and to the system user. Multiplexed address inputs permit the TC5116100BSJ to be packaged in a standard 26/24 pin plastic SOJ (300mil). The package size provides high system bit densities and is compatible with widely available automated testing and insertion equipment. System oriented features include single power supply of 5V± 10% tolerance, direct interfacing capability with high performance logic families such as Schottky TTL.

#### **Features**

- 16,777,216 word by 1 bit organization
- · Fast access time and cycle time
- Single power supply of 5V± 10% with a built-in V<sub>BB</sub> generator
- Low Power
  - 440mW MAX. Operating
  - (TC5116100BSJ-60)
  - 385mW MAX. Operating
  - (TC5116100BSJ-70)
  - 5,5mW MAX. Standby
- Outputs unlatched at cycle end allows twodimensional chip selection
- Common I/O capability using "EARLY WRITE" operation
- Read-Modify-Write, CAS before RAS refresh, RAS-only refresh, Hidden refresh, Fast Page Mode and Test Mode capability
- All inputs and outputs TTL compatible
- 4096 refresh cycles/64ms
- Package TC5116100BSJ: SOJ26-P-300C

Note: For packaging details see Mechanical Dimensions section.

#### **Key Parameters**

	ITEM	TC5116	100BSJ
	11 EIVI	-60	-70
t <sub>RAC</sub>	RAS Access Time	60ns	70ns
t <sub>AA</sub>	Column Address Access Time	30ns	35ns
tCAC	CAS Access Time	15ns	20ns
t <sub>RC</sub>	Cycle Time	110ns	130ns
t <sub>PC</sub>	Fast Page Mode Cycle Time	40ns	45ns

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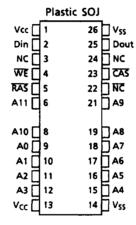
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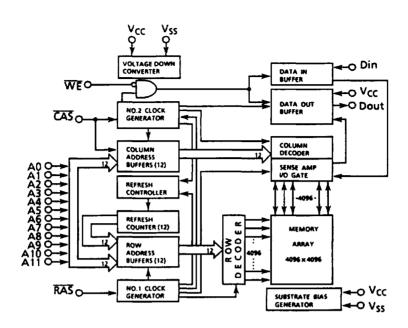
#### Pin Name

A0 ~ A11	Address Inputs
RAS	Row Address Strobe
CAS	Column Address Strobe
WE	Write Enable
D <sub>IN</sub>	Data In
D <sub>OUT</sub>	Data Out
V <sub>CC</sub>	Power (+5V)
V <sub>SS</sub>	Ground
N.C.	No Connection

#### Pin Connection (Top View)



#### **Block Diagram**



#### **Absolute Maximum Ratings**

ITEM	SYMBOL	RATING	UNIT	NOTE
Input Voltage	V <sub>IN</sub>	-0.5~V <sub>CC</sub> +0.5	ν	1
Output Voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> +0.5	V	1
Power Supply Voltage	V <sub>CC</sub>	-0.5~7.0	V	1
Operating Temperature	T <sub>OPR</sub>	0~70	°C	1
Storage Temperature	T <sub>STG</sub>	-55~150	°C	1
Soldering Temperature (10s)	T <sub>SOLDER</sub>	260	°C	1
Power Dissipation	PD	900	mW	1
Short Circuit Output Current	lout	50	mA	1

## Recommended DC Operating Conditions (Ta = 0 ~ 70°C)

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT	NOTE
Vcc	Power Supply Voltage	4.5	5.0	5.5	٧	2
V <sub>IH</sub>	Input High Voltage	2.4	-	V <sub>CC</sub> + 0.5*	٧	2
V <sub>IL</sub>	Input Low Voltage	-0.5**	-	0.8	٧	2

 $<sup>^*</sup>V_{CC}$  + 2.0V at pulse width  $\le$  20ns (pulse width is measured at  $V_{CC}$ ).  $^{**}$ -2.0V at pulse width  $\le$  20ns (pulse width is measured at  $V_{SS}$ ).

## DC Electrical Characteristics ( $V_{CC} = 5V \pm 10\%$ , $Ta = 0 \sim 70^{\circ}C$ )

SYMBOL	PARAMETER	MIN	MAX	UNIT	NOTE	
	OPERATING CURRENT	TC5116100BSJ-60	-	80		3,4
l <sub>CC1</sub>	Average Power Supply Operating Current (RAS, CAS, Address Cycling: t <sub>RC</sub> =t <sub>RC</sub> MIN)	TC5116100BSJ-70	-	70	mA	5
l <sub>CC2</sub>	STANDBY CURRENT Power Supply Standby Current (RAS=CAS=V <sub>IH</sub> )		-	2	mA	
	RAS ONLY REFRESH CURRENT	TC5116100BSJ-60	-	- 80		
l <sub>CC3</sub>	Average Power Supply Current, RAS Only Mode (RAS Cycling, CAS=V <sub>IH</sub> : t <sub>RC</sub> =t <sub>RC</sub> MIN.)	TC5116100BSJ-70	-	70	mA	3, 5
	FAST PAGE MODE CURRENT T		-	70		3,4
I <sub>CC4</sub>	Average Power Supply Current, Fast Page Mode (RAS =V <sub>IL</sub> . CAS, Address Cycling: t <sub>PC</sub> =t <sub>PC</sub> MIN.)	TC5116100BSJ-70	-	60	mA	5
l <sub>CC5</sub>	STANDBY CURRENT Power Supply Standby Current (RAS=CAS=V <sub>CC</sub> -0.2V)	_	1	mA		
	CAS BEFORE RAS REFRESH CURRENT	TC5116100BSJ-60	-	80		
I <sub>CC6</sub>	Average Power Supply Current, CAS Before RAS Mode (RAS, CAS, Cycling: t <sub>RC</sub> ≃t <sub>RC</sub> MIN.)	TC5116100BSJ-70	-	70	mA !	3, 5
l <sub>I (L)</sub>	INPUT LEAKAGE CURRENT Input Leakage Current, any input (0V <v<sub>IN<v<sub>CC, All Other Pins Not Under Test=0V)</v<sub></v<sub>		-10	10	μА	
l <sub>O (L)</sub>	OUTPUT LEAKAGE CURRENT (D <sub>OUT</sub> is disabled, (0V≤V <sub>OUT</sub> <v<sub>CC)</v<sub>		-10	10	μА	
V <sub>OH</sub>	OUTPUT LEVEL Output "H" Level Voltage (I <sub>OUT</sub> =-5mA)			-	V	
V <sub>OL</sub>	OUTPUT LEVEL Output "L" Level Voltage (I <sub>OUT</sub> =4.2mA)			0.4	V	

# Electrical Characteristics and Recommended AC Operating Conditions ( $V_{CC} = 5V \pm 10\%$ , $Ta = 0 \sim 70^{\circ}C$ ) (Notes 6,7,8)

	PARAMETER	T	TC5116	100BSJ		UNIT	NOTES
SYMBOL			-60		-70		
		MIN	MAX.	MIN	MAX		
t <sub>RC</sub>	Random Read or Write Cycle Time	110	-	130	-	ns	
t <sub>RMW</sub>	Read-Modify-Write Cycle	130	-	155		ns	
t <sub>PC</sub>	Fast Page Mode Cycle Time	40	-	45	-	ns	
t <sub>PRMW</sub>	Fast Page Mode Read-Modify-Write Cycle Time	60		70	-	ns	
t <sub>RAC</sub>	Access Time from RAS	-	60	-	70	ns	9,14, 15
t <sub>CAC</sub>	Access Time from CAS	<u> </u>	15	-	20	ns	9,14
t <sub>AA</sub>	Access Time from Column Address	† -	30	-	35	ns	9,15
t <sub>CPA</sub>	Access Time from CAS Precharge	-	35	-	40	-	9
t <sub>CLZ</sub>	CAS to Output in Low-Z	0	-	0	-	ns	9
t <sub>OFF</sub>	Output Buffer Turn-off Delay	0	15	0	15	ns	10
t <sub>T</sub>	Transition Time (Rise and Fall)	3	50	3	50	ns	8
t <sub>RP</sub>	RAS Precharge Time	40		50	-	ns	
t <sub>RAS</sub>	RAS Pulse Width	60	10,000	70	10,000	ns	
tRASP	RAS Pulse Width (Fast Page Mode)	60	400,000	70	400,000	ns	
t <sub>RSH</sub>	RAS Hold Time	15	- 1	20	-	ns	
t <sub>RHCP</sub>	RAS Hold Time from CAS Precharge (Fast Page Mode)	35		40		ns	
t <sub>CSH</sub>	CAS Hold Time	60	-	70	-	ns	
t <sub>CAS</sub>	CAS Pulse Width	15	10,000	20	10,000	ns	1
t <sub>RCD</sub>	RAS to CAS Delay Time	20	45	20	50	ns	14
t <sub>RAD</sub>	RAS to Column Address Delay Time	15	30	15	35	ns	15
t <sub>CRP</sub>	CAS to RAS Precharge Time	5	-	5		ns	
t <sub>CP</sub>	CAS Precharge Time	10	† <u>-</u>	10		ns	<u> </u>
t <sub>ASR</sub>	Row Address Set-Up Time	0	-	0	-	ns	
t <sub>RAH</sub>	Row Address Hold Time	10	-	10	-	ns	
t <sub>ASC</sub>	Column Address Set-Up Time	0	-	0	-	ns	
t <sub>CAH</sub>	Column Address Hold Time	10	-	15	-	ns	
t <sub>RAL</sub>	Column Address to RAS Lead Time	30	-	35	-	ns	
t <sub>RCS</sub>	Read Command Set-Up Time	0	-	0	-	ns	
t <sub>RCH</sub>	Read Command Hold Time	0	-	0	-	ns	11
t <sub>RRH</sub>	Read Command Hold Time referenced to RAS	0	-	0	-	ns	11
twch	Write Command Hold Time	10	-	15	-	ns	



#### **Electrical Characteristics and Recommended AC Operating Conditions (Cont)**

			TC5116				
SYMBOL	PARAMETER	-	-60		70	UNIT	NOTES
		MIN	MAX.	MIN	MAX		
t <sub>WP</sub>	Write Command Pulse Width	10		15	-	ns	
t <sub>RWL</sub>	Write Command to RAS Lead Time	15	-	20	-	ns	
t <sub>CWL</sub>	Write Command to CAS Lead Time	15	-	20	-	ns	
t <sub>DS</sub>	Data Set-Up Time	0	-	0	-	ns	12
t <sub>DH</sub>	Data Hold Time	10	-	15	-	ns	12
t <sub>REF</sub>	Refresh Period	-	64		64	ms	
twcs	Write Command Set-Up Time	0	-	0	-	ns	13
tcwD	CAS to WE Delay Time	15		20		ns	13
t <sub>RWD</sub>	RAS to WE Delay Time	60	-	70		ns	13
t <sub>AWD</sub>	Column Address to WE Delay Time	30	-	35	-	ns	13
t <sub>CPWD</sub>	CAS Precharge to WE Delay Time	35	-	40	-	ns	13
t <sub>CSR</sub>	CAS Set-up Time (CAS before RAS Cycle)	5	-	5	-	ns	
t <sub>CHR</sub>	CAS Hold Time (CAS before RAS Cycle)	10	-	15	-	ns	
t <sub>RPC</sub>	RAS to CAS Precharge Time	5	-	5	-	ns	
t <sub>CPT</sub>	CAS Precharge Time (CAS before RAS Counter Test Cycle	20	-	30	-	ns	
twrs	Write Command Set-up Time (Test Mode In)	10	-	10	-	ns	
t <sub>WTH</sub>	Write Command Hold Time (Test Mode In)	10	-	10	-	ns	
t <sub>WRP</sub>	WE to RAS Precharge Time (CAS before RAS Cycle)	10	-	10	-	ns	
t <sub>WRH</sub>	WE to RAS Hold Time (CAS before RAS Cycle)	10	_	10	-	ns	

## Electrical Characteristics and Recommended AC Operating Conditions in the Test Mode

	PARAMETER		TC5116				
SYMBOL		-60		-70		UNIT	NOTES
		MIN	MAX.	MIN	MAX	1	
t <sub>RC</sub>	Random Read or Write Cycle Time	115	-	135	-	ns	
t <sub>PC</sub>	Fast Page Mode Cycle Time	45	-	50	-	ns	
t <sub>RAC</sub>	Access Time from FAS	-	65	-	75	ns	9, 14, 15
t <sub>CAC</sub>	Access Time from CAS	-	20	-	25	ns	9, 14
t <sub>AA</sub>	Access Time from Column Address	-	35	-	40	ns	9, 15
t <sub>CPA</sub>	Access Time from CAS Precharge	-	40	-	45	ns	9
t <sub>RAS</sub>	RAS Pulse Width	65	10,000	75	10,000	ns	
tRASP	RAS Pulse Width (Fast Page Mode)	65	400,000	75	400,000	ns	
t <sub>RSH</sub>	RAS Hold Time	20	-	25	-	ns	
t <sub>CSH</sub>	CAS Hold Time	65	-	75	-	ns	
t <sub>RHCP</sub>	RAS Hold Time from CAS Precharge (Fast Page Mode)	40	-	45	-	ns	
tCAS	CAS Pulse Width	20	10,000	25	10,000	ns	
tRAL	Column Address to RAS Lead Time	35	-	40	-	ns	-

## Capacitance ( $V_{CC} = 5V \pm 10\%$ , f = 1MHz, Ta = 0 ~ 70°C)

SYMBOL	PARAMETER	MIN	MAX	UNIT
C <sub>I1</sub>	Input Capacitance (A0~A10, D <sub>IN</sub> )	-	5	
C <sub>I2</sub>	Input Capacitance (RAS, CAS, WE)	-	7	₽F
Co	Input Capacitance (D <sub>OUT</sub> )	-	7	

Note: Please refer to Timing Diagrams Number 3.

#### Notes:

- 1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.
- 2. All voltages are referenced to Vss.
- 3. Icc1, Icc3, Icc4, Icc6 depend on cycle rate.
- 4. I<sub>CC1</sub>, I<sub>CC4</sub> depend on output loading. Specified values are obtained with the output open.
- 5. Address can be changed one or less while RAS=VIL. In case of I<sub>CC4</sub>, it can be changed once or less during a fast page mode cycle (t<sub>PC</sub>).
- 6. An initial pause of 200µs is required after power-up followed by 8 RAS only refresh cycles before proper device operation is achieved. In case of using internal refresh counter, a minimum of 8 CAS before RAS refresh cycles instead of 8 RAS only refresh cycles are required.
- 7. AC measurements assume t<sub>+</sub>=5ns.
- 8.  $V_{IH}$  (min.) and  $V_{II}$  (max.) are reference levels for measuring timing of input signals. Also, transition times are measured between  $V_{IH}$  and  $V_{II}$ .
- 9. Measured with a load equivalent to 2 TTL loads and 100pF.
- 10. tope (max.) defines the time at which the output achieves the open circuit condition and is not referenced to output voltage levels.
- 11. Either t<sub>BCH</sub> or t<sub>BBH</sub> must be satisfied for a read cycle.
- 12. These parameters are referenced to CAS leading edge in early write cycles and to WE leading edge in Read-Modify-Write cycles.
- 13. t<sub>WCS</sub>, t<sub>RWD</sub>, t<sub>CWD</sub>, t<sub>AWD</sub> and t<sub>CPWD</sub> are not restrictive operating parameters. They are included in the data sheet as electrical characteristics only. If t<sub>WCS</sub> ≥t<sub>WCS</sub> (min.), the cycle is an early write cycle and the data out pin will remain open circuit (high impedance) through the entire cycle; If t<sub>RWD</sub>≥t<sub>RWD</sub> (min.), t<sub>CWD</sub>≥t<sub>CWD</sub> (min.), t<sub>AWD</sub>≥t<sub>AWD</sub> (min.) and t<sub>CPWD</sub>≥t<sub>CPWD</sub> (min.) (Fast Page Mode), the cycle is a Read-Modify-Write cycle and the data out will contain data read from the selected cell; If neither of the above sets of conditions are satisfied, the condition of the data out (at access time) is indeterminate.
- 14. Operation within the t<sub>RCD</sub> (max.) limit insures that t<sub>RAC</sub> can be met. t<sub>RCD</sub> (max.) is specified as a reference point only: If t<sub>RCD</sub> is greater than the specified t<sub>RCD</sub> (max.) limit, then access time is controlled by t<sub>CAC</sub>.
- 15. Operation within the t<sub>RAD</sub> (max.) limit insures that t<sub>RAD</sub> (max.) can be met. t<sub>RAD</sub> (max.) is specified as a reference point only: If t<sub>RAD</sub> is greater than the specified t<sub>RAD</sub> (max.) limit, then access time is controlled by t<sub>AA</sub>.